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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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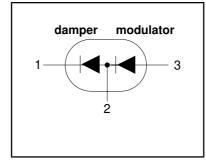


BYM357X

FEATURES

- · Low forward volt drop
- Fast switchingSoft recovery characteristicHigh thermal cycling
- performance
- Isolated mounting tab

SYMBOL



QUICK REFERENCE DATA

DAMPER	MODULATOR
V _R =1500 V	V _R =600 V
$V_F \leq 1.3 \text{ V}$	V _F ≤ 1.03 V
I _{F(peak)} =7 A	$I_{F(peak)} = 7 A$
I _{FSM} ≤ 60 A	I _{FSM} ≤ 70 A
t _{rr} ≤ 300 ns	t _{rr} ≤ 60 ns

GENERAL DESCRIPTION

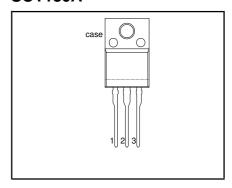
Combined damper and modulator diodes in an isolated plastic envelope for horizontal deflection in colour TV and PC monitors. The BYM357X contains diodes with performance characteristics designed specifically for applications from 16kHz to 70kHz

The BYM357X series is supplied in the conventional leaded SOT186A package.

PINNING

PIN	DESCRIPTION
1	damper cathode
2	common anode/cathode
3	modulator anode.

SOT186A



LIMITING VALUES

T_i = 25 °C unless otherwise stated

			DAM	PER	MODUI	LATOR	
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	MIN	MAX	UNIT
V _{RSM}	Peak non-repetitive reverse voltage.		-	1500	-	600	٧
V_{RRM}	Peak repetitive reverse voltage		-	1500	-	600	V
V_{RWM}	Crest working reverse voltage		-	1300	-	600	V
I _{F(peak)}	Peak forward current	31-70 kHz monitor.	-	7	-	7	Α
I _{F(RMS)}	RMS forward current	sinusoidal;a=1.57	-	15.7	-	14.1	Α
I _{FSM}	Peak non-repetitive forward current	$\begin{array}{l} t = 10 \text{ ms} \\ t = 8.3 \text{ ms} \\ \text{sinusoidal;with} \\ \text{reapplied} \\ V_{\text{RWM(MAX)}} \end{array}$	- -	60 66	-	70 77	A A
T _{stg}	Storage temperature Operating junction temperature		-40 -	150 150	-40 -	150 150	Ů,

Philips Semiconductors Product specification

Damper-Modulator fast, high-voltage

BYM357X

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	-	-	2500	٧
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

			DAM	IPER	MODU	LATOR	
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	TYP.	MAX.	UNIT
R _{th j-hs}	Thermal resistance junction to heatsink	with heatsink compound	-	4.8	-	5.5	K/W
R _{th j-a}	Thermal resistance junction to ambient	in free air.	55	-	55	-	K/W

STATIC CHARACTERISTICS OF DAMPER

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP	MAX.	UNIT
V _F	Forward voltage Reverse current	$ \begin{aligned} I_F &= 6.5 \text{ A} \\ I_F &= 6.5 \text{ A}; T_j = 125 ^{\circ}\text{C} \\ V_R &= V_{RWM} \\ V_R &= V_{RWM} \\ T_j &= 100 ^{\circ}\text{C} \end{aligned} $	1.1 1.05 10 50	1.45 1.3 250 500	V ν μΑ μΑ

STATIC CHARACTERISTICS OF MODULATOR

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP	MAX.	UNIT
V _F	Forward voltage Reverse current.	$ \begin{array}{l} I_F = 8 \text{ A} \\ I_F = 8 \text{ A}; T_j = 125^{\circ}\text{C} \\ I_F = 20 \text{ A} \\ V_R = V_{RWM} \\ V_R = V_{RWM} \\ T_j = 100 ^{\circ}\text{C} \\ \end{array} $	1.05 0.9 1.3 10 100	1.25 1.03 1.45 50 350	V V V μΑ μΑ

BYM357X

ELECTRICAL CHARACTERISTICS OF DAMPER

T_i = 25 °C unless otherwise stated

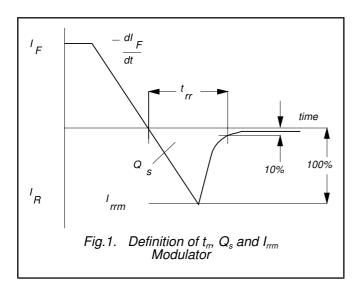
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$	200	300	ns
$egin{pmatrix} Q_s \ V_{fr} \end{pmatrix}$	Reverse recovery charge Peak forward recovery voltage	$-dI_{F}/dt = 50 \text{ A/}\mu\text{s}$ 2 A,30 V,20 A/ μ s $I_{F} = 6.5 \text{ A};$ $dI_{F}/dt = 50 \text{ A/}\mu\text{s}$	1.2 27	2.0	μC V

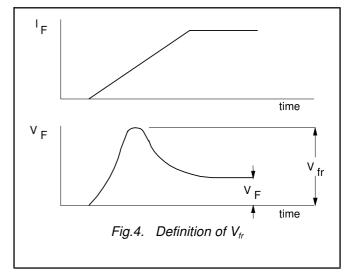
ELECTRICAL CHARACTERISTICS OF MODULATOR

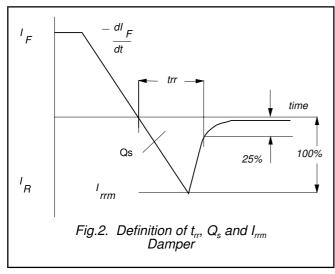
T_i = 25 °C unless otherwise stated

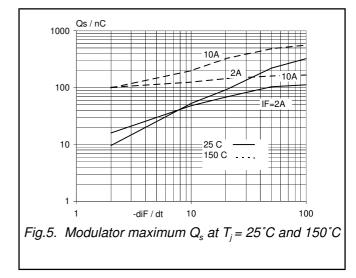
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V}; \\ -dI_F/dt = 100 \text{ A}/\mu\text{s}$	35	60	ns
I _{rrm}	Peak reverse recovery current	$I_F = 10 \text{ A to V}_R \ge 30 \text{ V};$ $dI_F/dt = 50 \text{ A/}\mu\text{s}; T_i = 100 ^{\circ}\text{C}$	3.0	5.5	Α
$egin{array}{c} Q_s \ V_{fr} \end{array}$	Reverse recovery charge Peak forward recovery voltage	2 A,30 V,20 A/μs I _F = 10 A; dI _F /dt = 10 A/μs	40 3.2	70 -	nC V

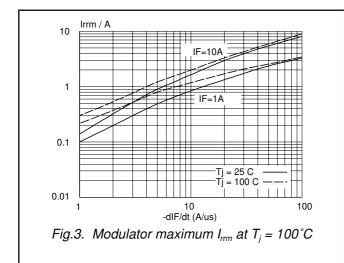
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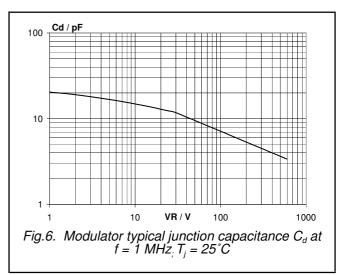




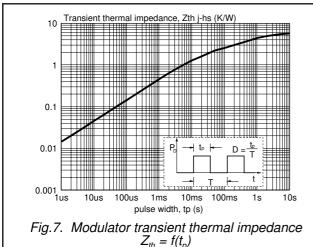






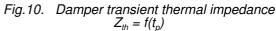


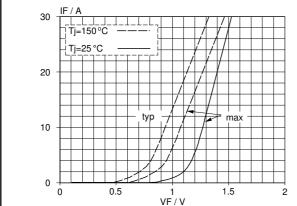
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0.1 0.01 100ms pulse width, tp (s)

 $Z_{th} = f(t_p)$





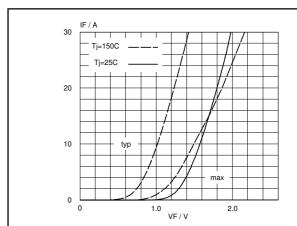


Fig.8. Modulator typical and maximum forward characteristic; $I_F = f(V_F)$; parameter T_j

Fig.11. Damper forward characteristic $I_F = f(V_F)$; parameter T_j

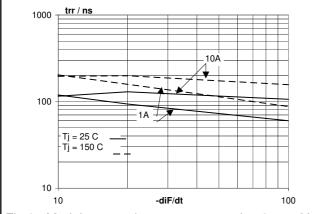
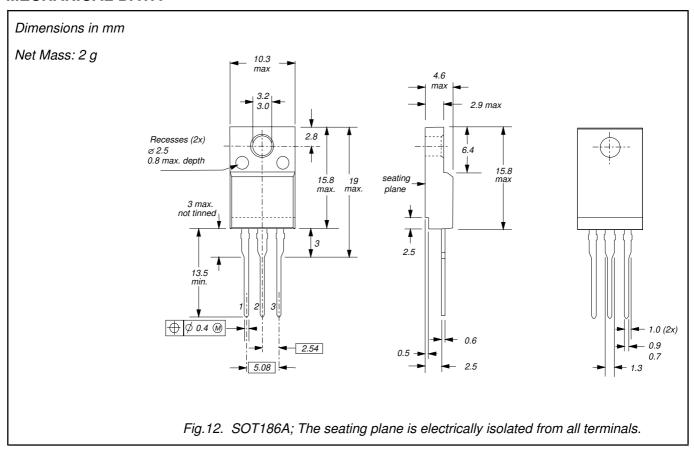


Fig.9. Modulator maximum t_{rr} measured to 25% of I_{rrm} ; $T_j = 25^{\circ}\text{C}$ and 150 $^{\circ}\text{C}$

BYM357X

MECHANICAL DATA



- Notes
 1. Refer to mounting instructions for F-pack envelopes.
 2. Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Damper-Modulator fast, high-voltage

BYM357X

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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